



## TO-262K Plastic-Encapsulate Thyristors

### CT408R 4Q TRIACs

#### MAIN CHARACTERISTICS

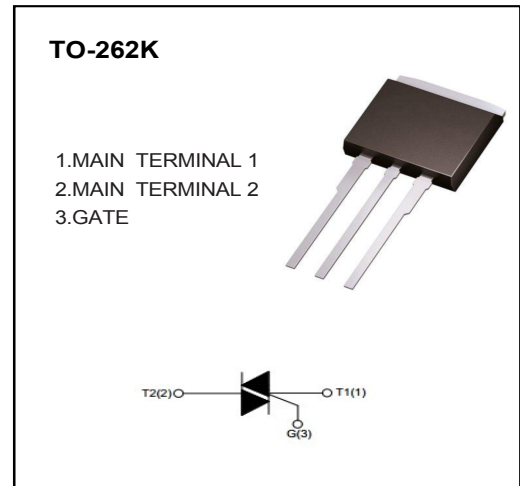
$I_{T(RMS)}$		8A
$V_{DRM}/V_{RRM}$	CT408R-600S/C	600V
	CT408R-800S/C	800V
$V_{TM}$		1.55V

#### FEATURES

- NPNPN 5-layer Structure TRIACs
- Mesa Glass Passivated Technology
- Multi Layers Metal Electrodes
- High Junction Temperature
- Good Commutation Performance

#### APPLICATIONS

- Heater Control
- Motor Speed Controller
- Mixer



#### MARKING



CT408R:Series Code  
 600S:Depends on  $V_{DRM}$   
 and  $I_{GT}$   
 XXX:Internal Code

#### ABSOLUTE RATINGS ( $T_a=25^{\circ}C$ unless otherwise noted )

Symbol	Parameter	Test condition	Value	Unit	
$V_{DRM}/V_{RRM}$	Repetitive peak off-state voltage	$T_j=25^{\circ}C$	CT408R-600S/C	600	V
			CT408R-800S/C	800	V
$I_{T(RMS)}$	RMS on-state current	TO-262K( $T_C \leq 105^{\circ}C$ ), Fig. 1,2	8	A	
$I_{TSM}$	Non repetitive surge peak on-state current	Full sine wave , $T_j(\text{init})=25^{\circ}C$ , $t_p=20\text{ms}$ ; Fig. 3,5	80	A	
$I^2t$	$I^2t$ value	$t_p=10\text{ms}$	36	$A^2s$	
$di_T/dt$	Critical rate of rise of on-state current	$I_G=2 \cdot I_{GT}$ , $t_r \leq 10\text{ns}$ , $F=120\text{Hz}$ , $T_j=125^{\circ}C$	I - II -III	50	$A/\mu s$
			IV	10	
$I_{GM}$	Peak gate current	$t_p=20\mu s$ , $T_j=125^{\circ}C$	2	A	
$P_{G(AV)}$	Average gate power	$T_j=125^{\circ}C$	0.5	W	
$T_{STG}$	Storage temperature		-40~+150	$^{\circ}C$	
$T_j$	Operating junction temperature		-40~+125		

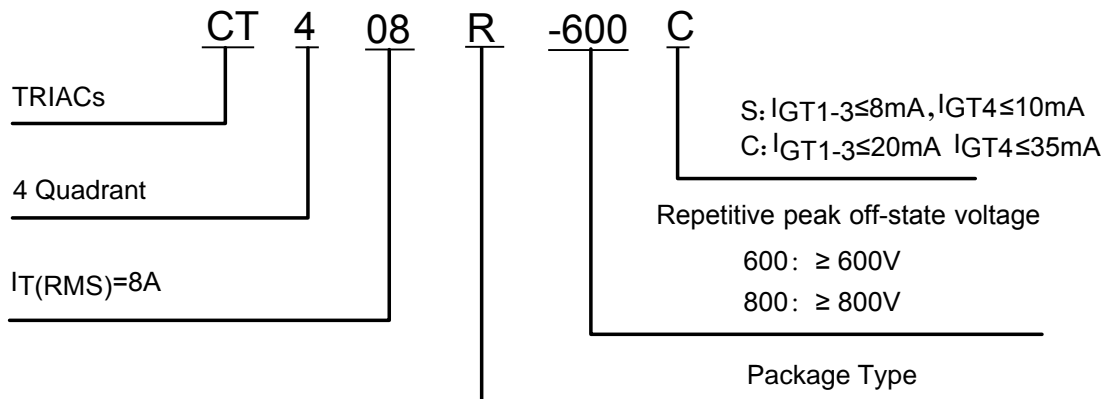
## ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C unless otherwise specified)

Symbol	Parameter	Test condition	Value		Unit	
			S	C		
I <sub>GT</sub>	Gate trigger current	V <sub>D</sub> =12V, I <sub>T</sub> =1A, T <sub>j</sub> =25°C, Fig. 6	I - II - III	≤8	≤20	mA
			IV	≤10	≤35	
V <sub>GT</sub>	Gate trigger voltage	T <sub>j</sub> =25°C, Fig. 6	I - II - III - IV	≤1.3		V
V <sub>GD</sub>	Non-triggering gate voltage	V <sub>D</sub> =V <sub>DRM</sub> , T <sub>j</sub> =125°C		≥0.2		V
I <sub>H</sub>	Holding current	V <sub>D</sub> =12V, I <sub>GT</sub> =0.1A, T <sub>j</sub> =25°C, Fig. 6	I - II - III - IV	≤10	≤20	mA
I <sub>L</sub>	Latching current		I - III - IV	≤15	≤25	mA
			II	≤20	≤35	mA
dV <sub>D</sub> /dt	Critical rate of rise of off-state	V <sub>D</sub> =67%V <sub>DRM</sub> , Gate Open T <sub>j</sub> =125°C		≥10	≥20	V/μs
V <sub>TM</sub>	On-state Voltage	I <sub>TM</sub> =10A, tp=380μs, Fig. 4		≤1.55		V
I <sub>DRM</sub> / I <sub>RPM</sub>	Repetitive peak off-state current	V <sub>D</sub> =V <sub>DRM</sub> /V <sub>RPM</sub> , T <sub>j</sub> =25°C		≤5	≤5	μA
		V <sub>D</sub> =V <sub>DRM</sub> /V <sub>RPM</sub> , T <sub>j</sub> =125°C		≤1	≤1	mA

## THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
R <sub>th</sub> (j-c)	Junction to case (AC)	TO-262K	1.6 °C/W
R <sub>th</sub> (j-a)	Junction to ambient	TO-262K	45 °C/W

## PART NUMBER



# CHARACTERISTICS CURVES

FIG.1: Maximum power dissipation versus RMS on-state current (full cycle)

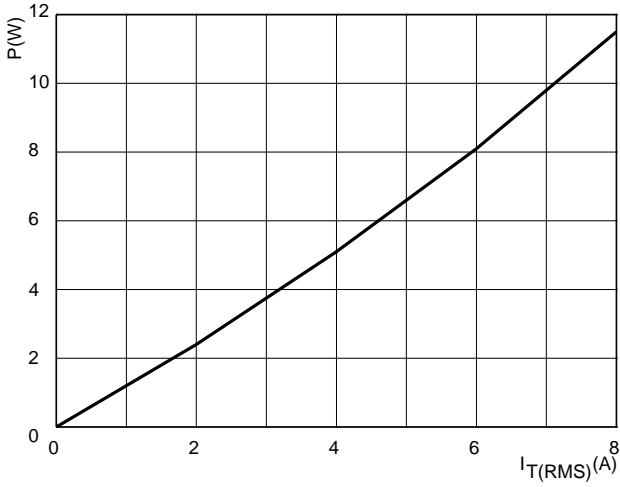


FIG.2: RMS on-state current versus case temperature (full cycle)

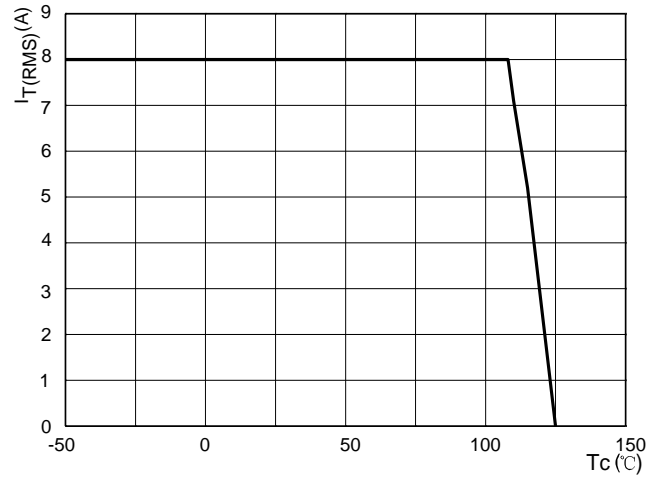


FIG.3: Surge peak on-state current versus number of cycles

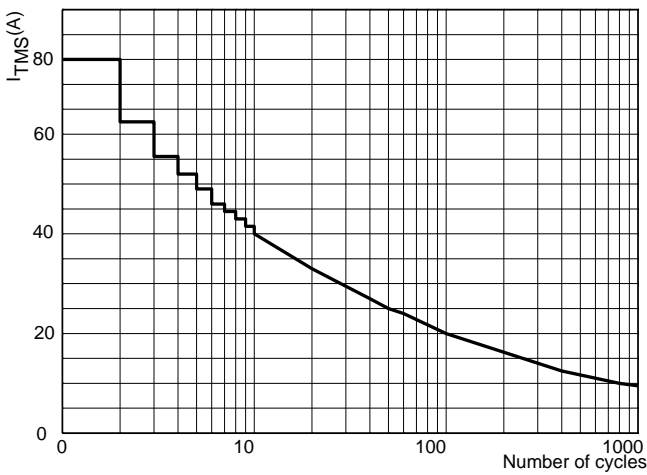


FIG.4: On-state characteristics (maximum values)

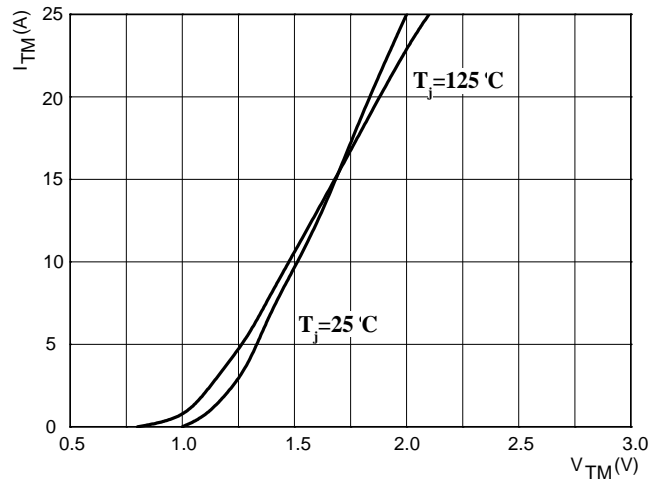


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 10\text{ms}$

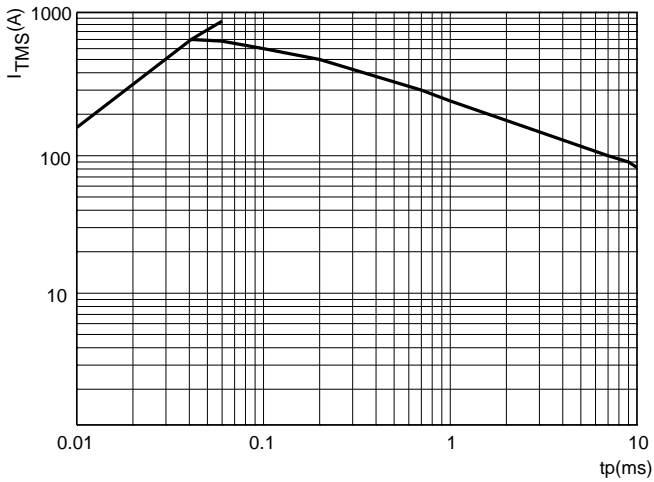
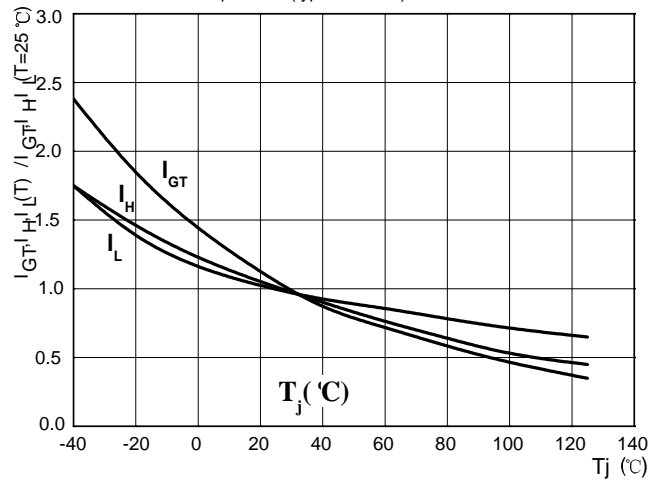
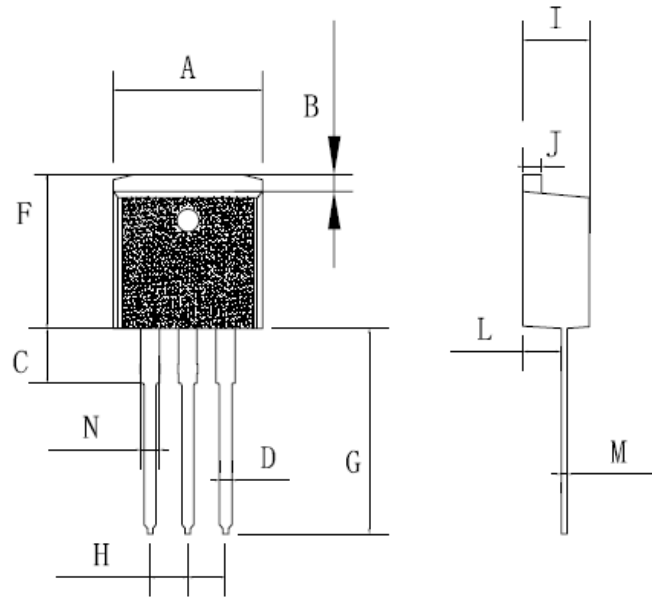


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature (typical values)



## TO-262K PACKAGE OUTLINE DIMENSIONS



DIM.	Unit(mm)		Unit(inch)	
	Min	Max	Min	Max
A	9.7	10.4	0.381	0.409
B	1.31	1.62	0.051	0.063
C	3.5	3.9	0.137	0.153
D	0.7	0.92	0.027	0.036
F	9.95	10.35	0.391	0.407
G	12.95	13.9	0.509	0.547
H	2.4	2.7	0.094	0.106
I	4.38	4.65	0.172	0.183
J	1.15	1.36	0.045	0.053
L	2.35	2.85	0.092	0.112
M	0.32	0.58	0.012	0.022
N	1.18	1.42	0.046	0.055

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